

**800mA LOW DROPOUT LINEAR REGULATOR****AZ1117B****General Description**

The AZ1117B is a low dropout three-terminal regulator with a dropout of 1.2V at 800mA output current.

The AZ1117B has been optimized for low voltage where transient response and minimum input voltage are critical. It provides current limit and thermal shutdown. Its circuit includes a trimmed bandgap reference to assure output voltage accuracy to be within  $\pm 1\%$ . On-chip thermal shutdown provides protection against a combination of high current and ambient temperature that would create excessive junction temperature.

The AZ1117B is available in 1.8V, 2.5V and 3.3V versions. The fixed versions integrate the adjust resistors. It is also available in an adjustable version which can set the output voltage with two external resistors.

The AZ1117B is available in the industry-standard SOT-223 power package.

**Features**

- Low Dropout Voltage: 1.2V at 800mA Output Current
- Output Noise from 10Hz to 10KHz: 0.003%
- PSRR at  $I_{OUT}=300mA$  and  $f=120Hz$ : 70dB
- Output Voltage Accuracy:  $\pm 1\%$
- On-chip Thermal Shutdown
- Maximum Quiescent Current:  $I_{QMAX}=6mA$
- Operation Junction Temperature: -20 to 105°C

**Applications**

- USB Device
- Add-on Card
- DVD Player
- PC Motherboard

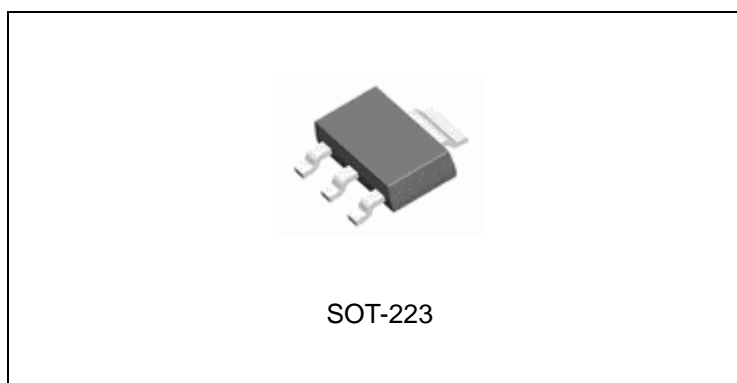


Figure 1. Package Type of AZ1117B



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Pin Configuration**

H Package  
(SOT-223)

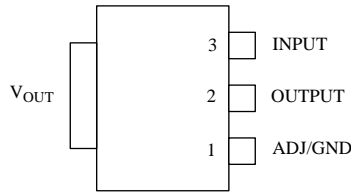


Figure 2. Pin Configuration of AZ1117B (Top View)

**Functional Block Diagram**

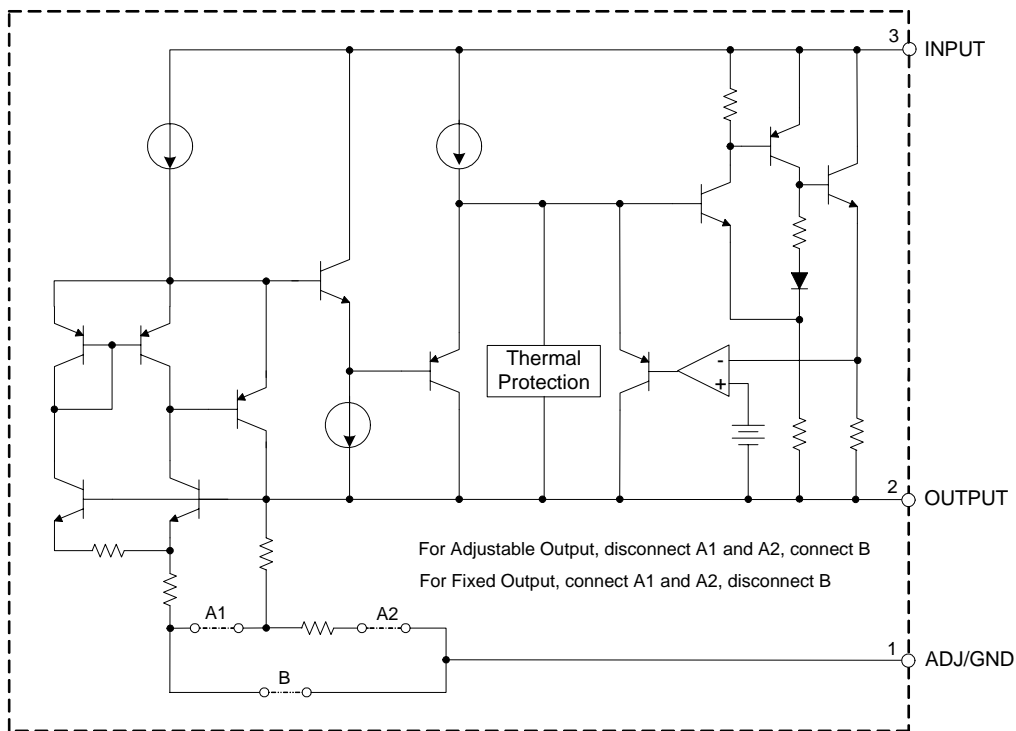


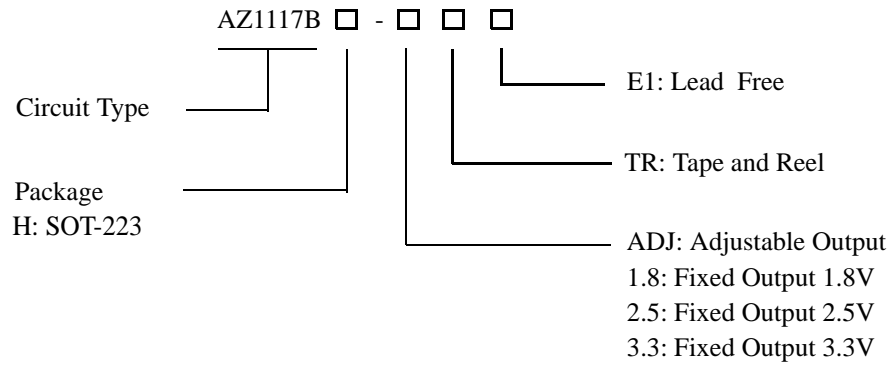
Figure 3. Functional Block Diagram of AZ1117B



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Ordering Information**



Package	Temperature Range	Part Number	Marking ID	Packing Type
SOT-223	-20 to 105°C	AZ1117BH-ADJTRE1	EH17K	Tape & Reel
		AZ1117BH-1.8TRE1	EH17L	Tape & Reel
		AZ1117BH-2.5TRE1	EH17N	Tape & Reel
		AZ1117BH-3.3TRE1	EH17M	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

**800mA LOW DROPOUT LINEAR REGULATOR****AZ1117B****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Input Voltage	$V_{IN}$	18	V
Operating Junction Temperature Range	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-65 to 150	°C
Lead Temperature (Soldering, 10sec)	$T_{LEAD}$	260	°C

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

**Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Input Voltage	$V_{IN}$		12	V
Operating Junction Temperature Range	$T_J$	-20	105	°C



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Electrical Characteristics**

**AZ1117B-ADJ Electrical Characteristics**

Operating Conditions:  $V_{IN}=V_{OUT}+2V$ ,  $I_{OUT}=10mA$ ,  $T_J=25^{\circ}C$ , unless otherwise specified. ( $P \leq$  maximum power dissipation).

Limits appearing in **Boldface** type apply over the entire junction temperature range for operation,  $-20^{\circ}C$  to  $105^{\circ}C$ .

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reference Voltage	$V_{REF}$		1.238	1.250	1.262	V
		$10mA \leq I_{OUT} \leq 800mA$ , $1.5V \leq V_{IN} - V_{OUT} \leq 10V$	<b>1.225</b>	1.250	<b>1.270</b>	
Line Regulation	$V_{RLINE}$	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.001	0.1	%
					<b>0.2</b>	
Load Regulation	$V_{RLOAD}$	$10mA \leq I_{OUT} \leq 800mA$		0.1	0.4	%
					<b>0.5</b>	
Dropout Voltage	$V_{DROP}$	$\Delta V_{REF}=1\%$ , $I_{OUT}=0.8A$		1.2	<b>1.3</b>	V
Current Limit	$I_{LIMIT}$		0.85	1	1.15	A
Adjust Pin Current				60	<b>120</b>	$\mu A$
Adjust Pin Current Change		$1.5V \leq (V_{IN} - V_{OUT}) \leq 10V$ , $10mA \leq I_{OUT} \leq 800mA$		0.2	<b>5</b>	$\mu A$
Minimum Load Current		$1.5V \leq (V_{IN} - V_{OUT}) \leq 10V$		1.7	<b>5</b>	mA
Ripple Rejection	PSRR	$f=120Hz$ , $C_{OUT}=22\mu F$ $(V_{IN} - V_{OUT})=3V$ , $I_{OUT}=300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of $V_{OUT}$ )		$T_A=25^{\circ}C$ , $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^{\circ}C$
Thermal Shutdown Hysteresis				16		$^{\circ}C$

**800mA LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-1.8V Electrical Characteristics**

Operating Conditions:  $V_{IN}=3.8V$ ,  $I_{OUT}=10mA$ ,  $T_J=25^{\circ}C$ , unless otherwise specified. ( $P \leq$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation,  $-20^{\circ}C$  to  $105^{\circ}C$ .

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	$V_{OUT}$		1.782	1.8	1.818	V
		$10mA \leq I_{OUT} \leq 800mA$ , $3.8V \leq V_{IN} \leq 10V$	<b>1.764</b>	1.8	<b>1.836</b>	
Line Regulation	$V_{RLINE}$	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					<b>10</b>	
Load Regulation	$V_{RLOAD}$	$10mA \leq I_{OUT} \leq 800mA$		2	10	mV
					<b>25</b>	
Dropout Voltage	$V_{DROP}$	$\Delta V_{OUT}=1\%$ , $I_{OUT}=0.8A$		1.2	<b>1.3</b>	V
Current Limit	$I_{LIMIT}$		0.85	1	1.15	A
Quiescent Current	$I_Q$	$I_{OUT}=0$		4	<b>6</b>	mA
Ripple Rejection	PSRR	$f=120Hz$ , $C_{OUT}=22\mu F$ $(V_{IN}-V_{OUT})=3V$ , $I_{OUT}=300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of $V_{OUT}$ )		$T_A=25^{\circ}C$ , $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^{\circ}C$
Thermal Shutdown Hysteresis				16		$^{\circ}C$

**800mA LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-2.5V Electrical Characteristics**

Operating Conditions:  $V_{IN}=4.5V$ ,  $I_{OUT}=10mA$ ,  $T_J=25^{\circ}C$ , unless otherwise specified. ( $P \leq$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation,  $-20^{\circ}C$  to  $105^{\circ}C$ .

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	$V_{OUT}$		2.475	2.5	2.525	V
		$10mA \leq I_{OUT} \leq 800mA$ , $4.5V \leq V_{IN} \leq 10V$	<b>2.455</b>	<b>2.5</b>	<b>2.545</b>	
Line Regulation	$V_{RLINE}$	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					<b>10</b>	
Load Regulation	$V_{RLOAD}$	$10mA \leq I_{OUT} \leq 800mA$		2	10	mV
					<b>25</b>	
Dropout Voltage	$V_{DROP}$	$\Delta V_{OUT}=1\%$ , $I_{OUT}=0.8A$		1.2	<b>1.3</b>	V
Current Limit	$I_{LIMIT}$		0.85	1	1.15	A
Quiescent Current	$I_Q$	$I_{OUT}=0$		4	<b>6</b>	mA
Ripple Rejection	PSRR	$f=120Hz$ , $C_{OUT}=22\mu F$ $(V_{IN}-V_{OUT})=3V$ , $I_{OUT}=300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of $V_{OUT}$ )		$T_A=25^{\circ}C$ , $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^{\circ}C$
Thermal Shutdown Hysteresis				16		$^{\circ}C$



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Electrical Characteristics (Continued)**

**AZ1117B-3.3V Electrical Characteristics**

Operating Conditions:  $V_{IN}=5.3V$ ,  $I_{OUT}=10mA$ ,  $T_J=25^{\circ}C$ , unless otherwise specified. ( $P \leq$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation,  $-20^{\circ}C$  to  $105^{\circ}C$ .

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	$V_{OUT}$		3.267	3.3	3.333	V
		$10mA \leq I_{OUT} \leq 800mA$ , $5.3V \leq V_{IN} \leq 10V$	<b>3.235</b>	3.3	<b>3.365</b>	
Line Regulation	$V_{RLINE}$	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					<b>10</b>	
Load Regulation	$V_{RLOAD}$	$10mA \leq I_{OUT} \leq 800mA$		2	10	mV
					<b>25</b>	
Dropout Voltage	$V_{DROP}$	$\Delta V_{OUT}=1\%$ , $I_{OUT}=0.8A$		1.2	<b>1.3</b>	V
Current Limit	$I_{LIMIT}$		0.85	1	1.15	A
Quiescent Current	$I_Q$	$I_{OUT}=0$		4	<b>6</b>	mA
Ripple Rejection	PSRR	$f=120Hz$ , $C_{OUT}=22\mu F$ $(V_{IN}-V_{OUT})=3V$ , $I_{OUT}=300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of $V_{OUT}$ )		$T_A=25^{\circ}C$ , $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^{\circ}C$
Thermal Shutdown Hysteresis				16		$^{\circ}C$





**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Typical Performance Characteristics**

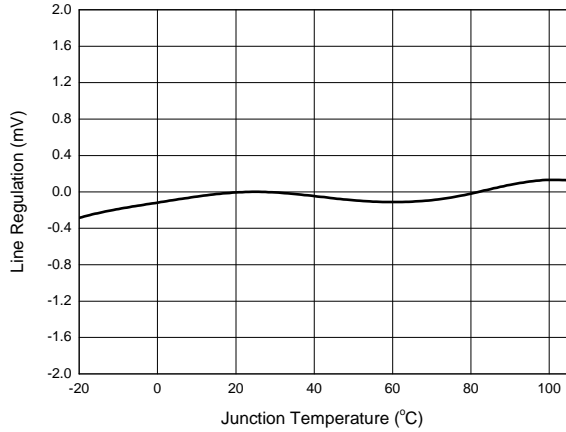


Figure 4. Line Regulation vs. Junction Temperature

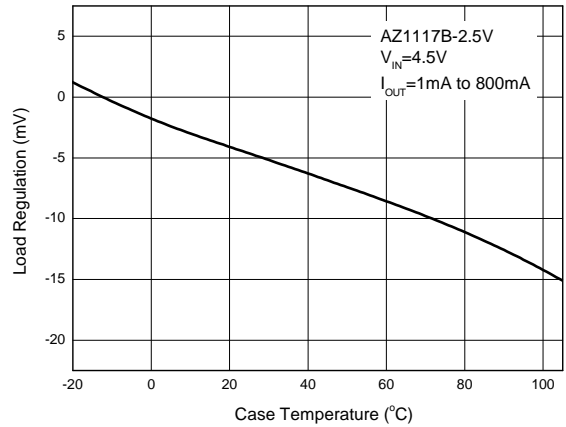


Figure 5. Load Regulation vs. Case Temperature

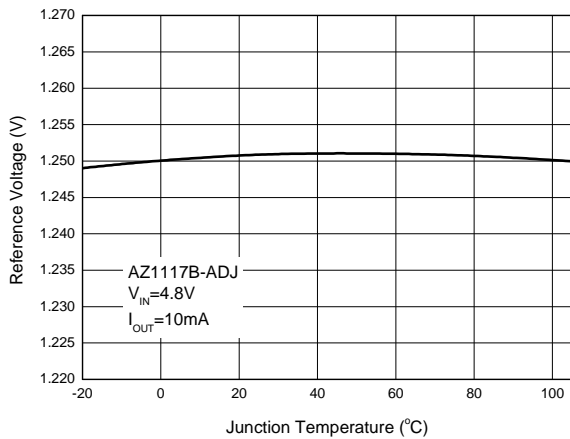


Figure 6. Reference Voltage vs. Junction Temperature

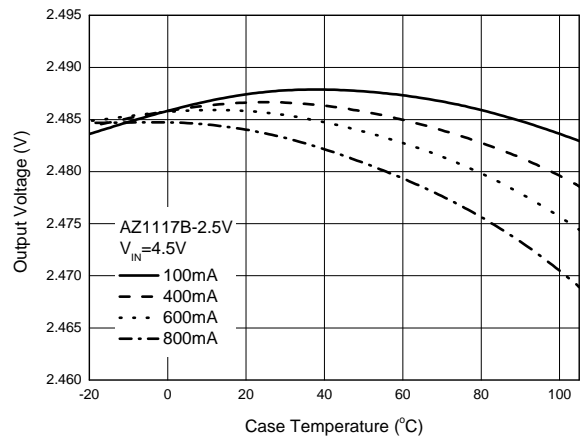


Figure 7. Output Voltage vs. Case Temperature



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Typical Performance Characteristics (Continued)**

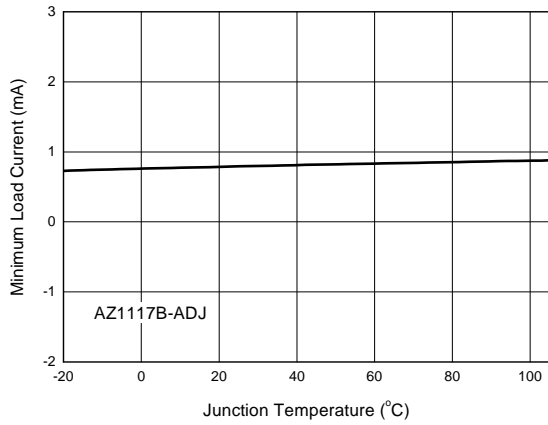


Figure 8. Minimum Load Current vs. Junction Temperature

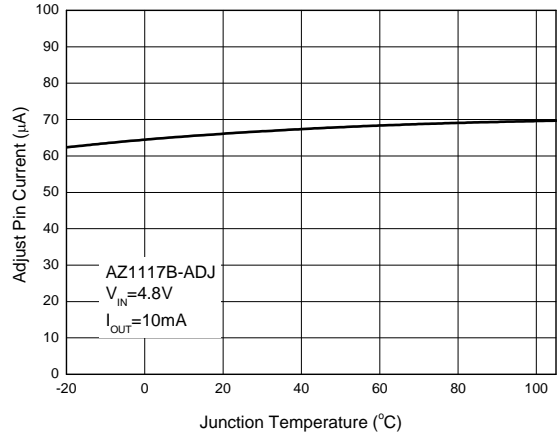


Figure 9. Adjust Pin Current vs. Junction Temperature

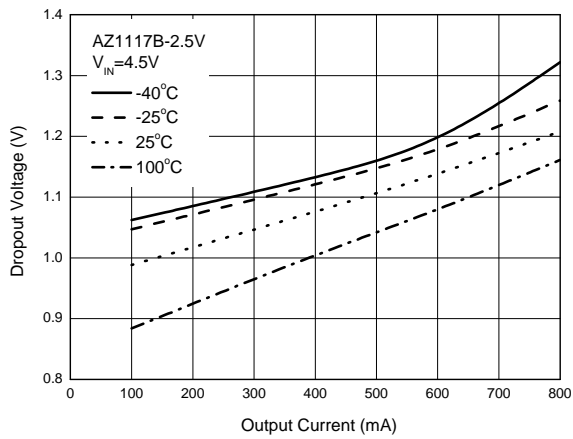


Figure 10. Dropout Voltage vs. Output Current

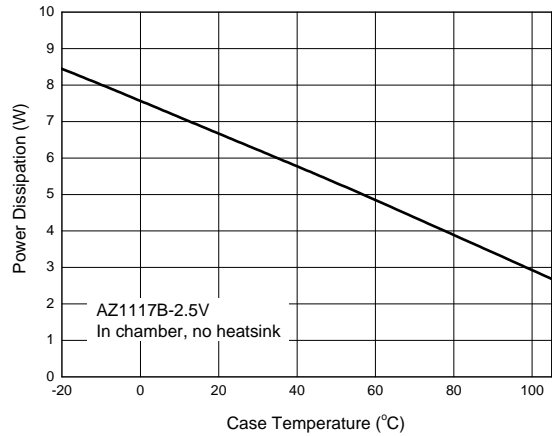


Figure 11. Power Dissipation vs. Case Temperature



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Typical Performance Characteristics (Continued)**

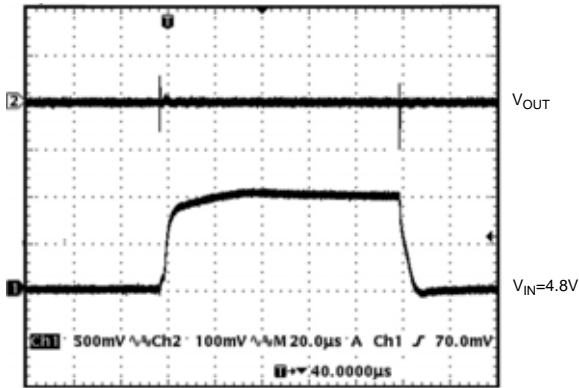


Figure 12. Line Transient Response

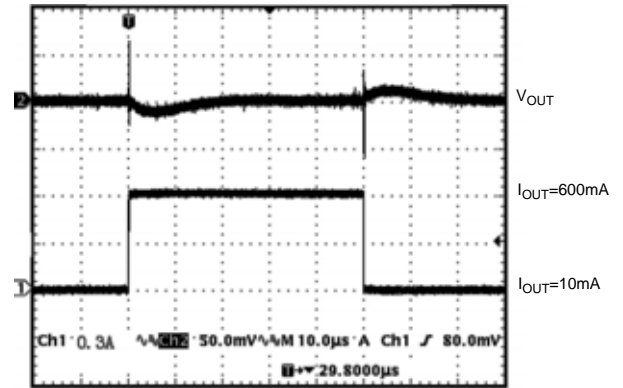


Figure 13. Load Transient Response

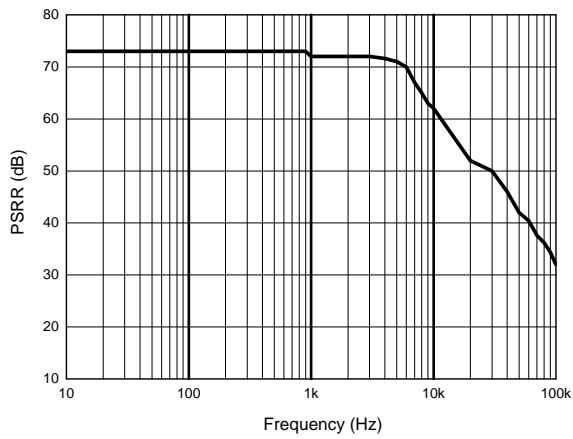


Figure 14. PSRR vs. Frequency

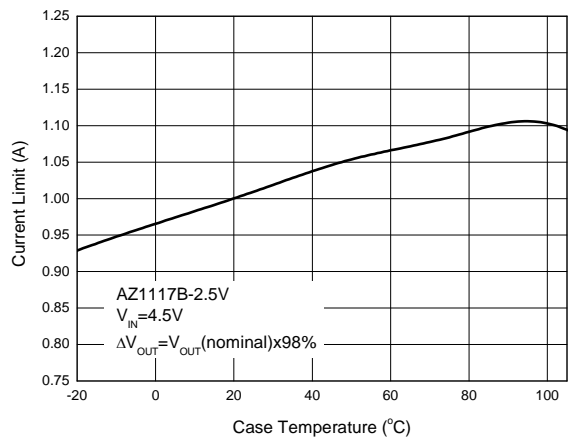


Figure 15. Current Limit vs. Case Temperature



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Typical Performance Characteristics (Continued)**

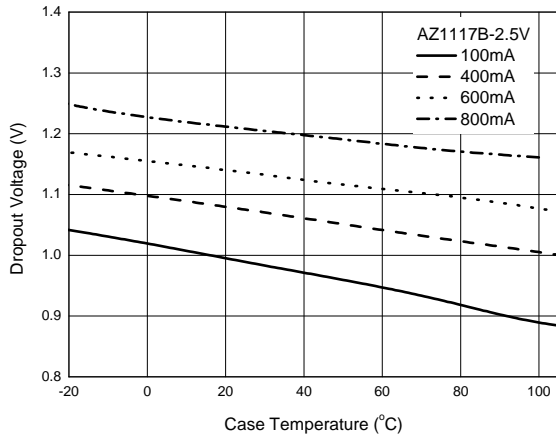


Figure 16. Dropout Voltage vs. Case Temperature

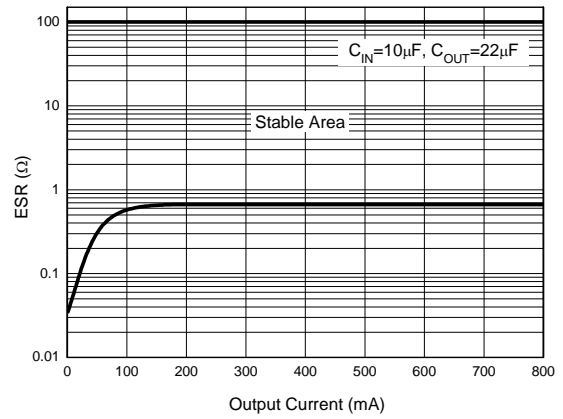


Figure 17. ESR vs. Output Current



**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Typical Applications**

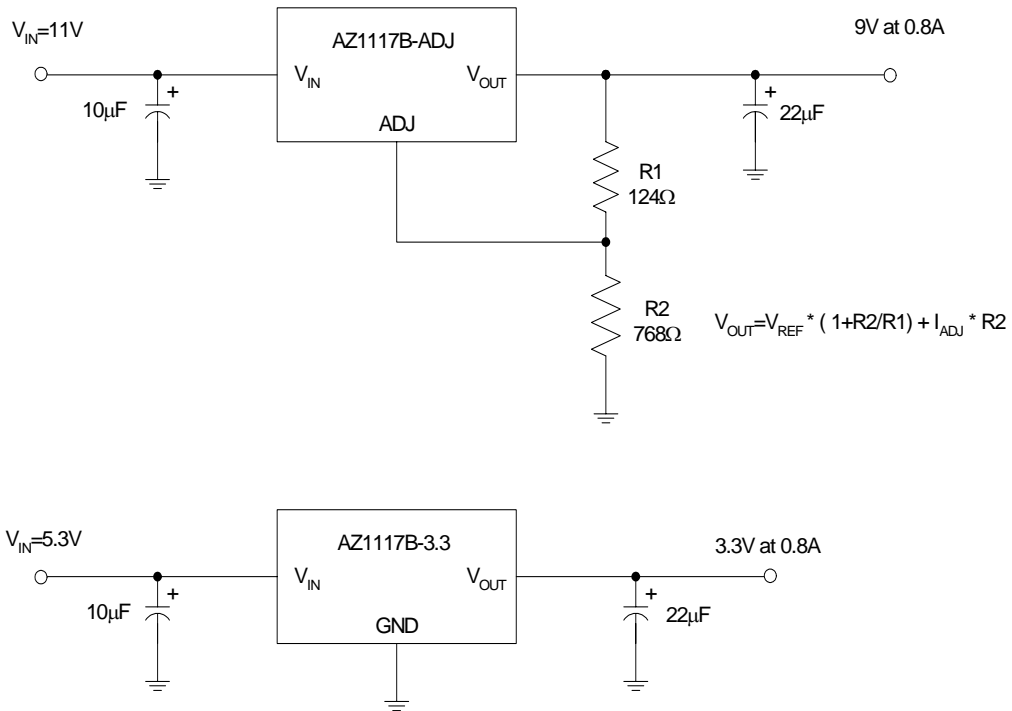


Figure 18. Typical Applications of AZ1117B



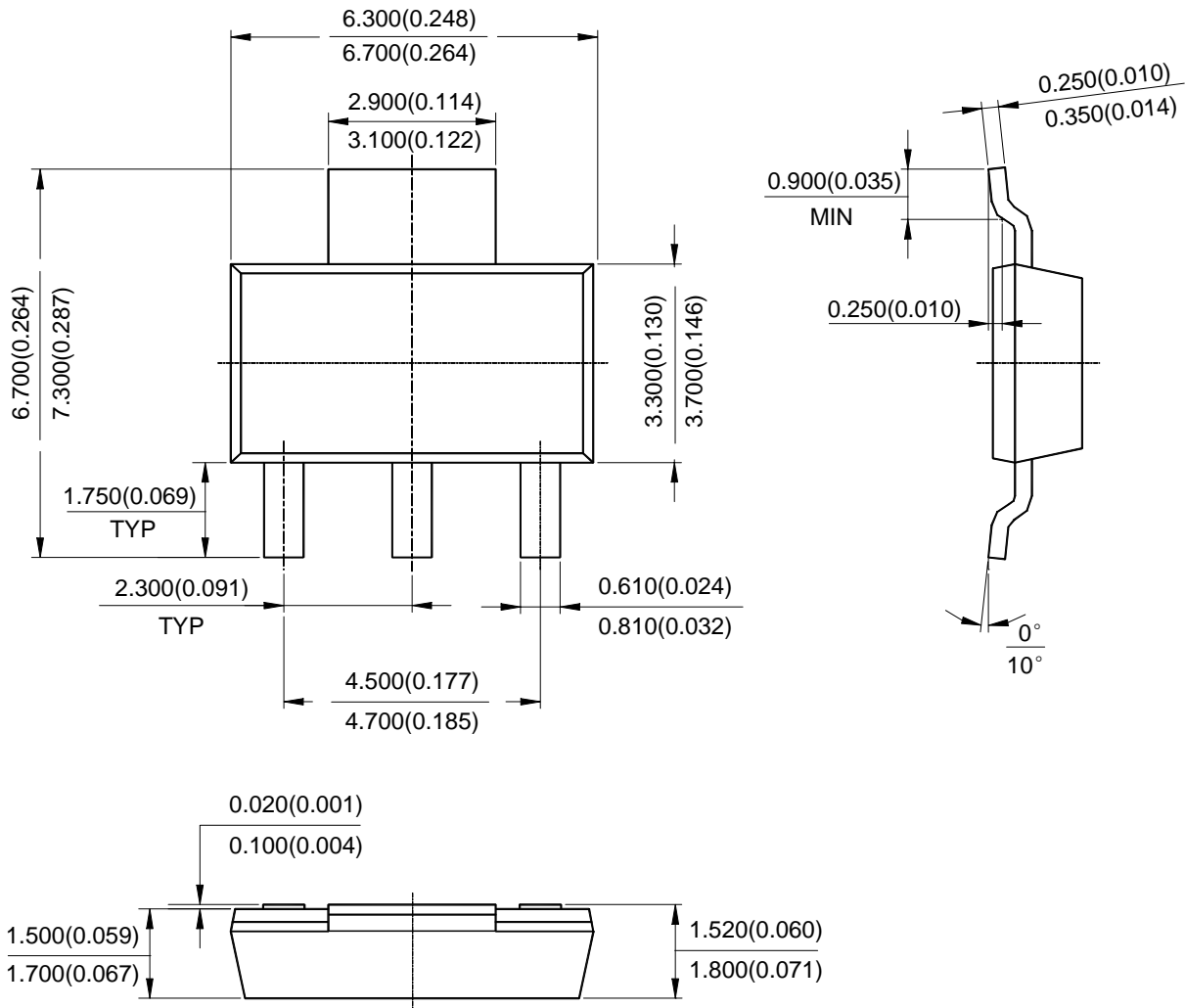
**800mA LOW DROPOUT LINEAR REGULATOR**

**AZ1117B**

**Mechanical Dimensions**

**SOT-223**

**Unit: mm(inch)**





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